U.S. PATENT DOCUMENTS							
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ar		5,852,318		Chikamatsu et. al.			
ON	, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	5,898,198		Herbert et al.			
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Application Number	09/752,396			
Filing Date	December 28, 2000			
First Named Inventor	Cheon-Soo Kim			
Group Art Unit	2811			
Examiner Name	Ori Nadav			
Attorney Docket Number	51876P231			

OTHER ART - NON PATENT LITERATURE DOCUMENTS						
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0 N		120 Watt, 2GHz, Si LDMOS RF Power Transistor For PCS Base Station Applications				
0~		High Performance Silicon LDMOS Technology For 2GHz RF Power Amplifier Applications				

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